

CRYSTALONCS
 2805 Veterans Highway
 Suite 14
 Ronkonkoma, N.Y. 11779

**HIGH-Q-HIGH VOLTAGE-HIGH CAPACITANCE
 SILICON EPITAXIAL VARACTRON
 VOLTAGE-VARIABLE CAPACITANCE DIODES**

**1N5714
 1N5715
 1N5716
 1N5717
 1N5718**

Electrically Equivalent to 1N5421-1N5425

GEOMETRY 417 or 419, GEOMETRY 419 or 423, GEOMETRY 423 or 418
 1N5714, 1N5715 1N5716, 1N5717 1N5718

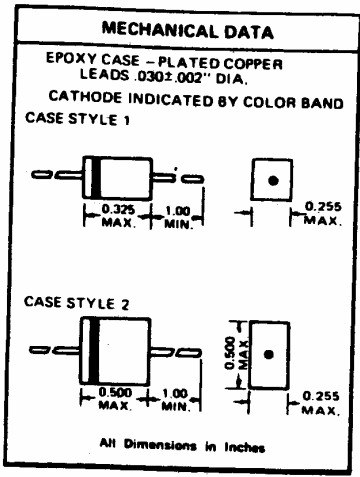
- EPITAXIAL CONSTRUCTION
- CAPACITANCE TO 1000 pF
- Q @ 25 MHZ TO 200
- V_{RM} (Working Voltage) TO 200 VOLTS

ABSOLUTE MAXIMUM RATINGS (ALL TYPES)

PARAMETER	SYMBOL	MAXIMUM	UNITS
Reverse Voltage	BV_R	As Indicated	Volts
Device Dissipation @ $T_A = 25^\circ C$	P_D	1	Watt
Operating Temperature	T_{opr}	-65 to +150	$^\circ C$
Storage Temperature	T_{stg}	-65 to +175	$^\circ C$

ELECTRICAL DATA ($T_A = 25^\circ C$) ALL TYPES UNLESS OTHERWISE NOTED

PARAMETER	SYMBOL	MIN.	MAX.	UNIT
Reverse Voltage Breakdown @ $I_R = 10 \mu A DC$	BV_R	As Indicated	-	Volts
Reverse Leakage Current @ Indicated V_{RM} (Wkg)	I_R	-	1.0	μA
Reverse Leakage Current @ Indicated V_{RM} (Wkg), $T_A = 150^\circ C$	I_R	-	125	μA
Temp. Coefficient of Capacitance $V_R = 5/8 VDC, f = 1MHz (-65^\circ C to +85^\circ C)$	T_{CC}	-	200	ppm/ $^\circ C$



ELECTRICAL CHARACTERISTICS: $T_A = 25^\circ C$ (UNLESS OTHERWISE NOTED)

Device Type	Nominal Capacitance (pF) $V_R = 4 VDC$ $f = 1MHz$	Nominal Capacitance (pF) $V_R = 8 VDC$ $f = 1MHz$	Minimum Tuning Ratio $V_{R1} = 4 VDC$ $V_{R2} = 100VDC$	Minimum Tuning Ratio $V_{R1} = 4 VDC$ $V_{R2} = 200VDC$	Minimum Working Voltage V_{RM} (Wkg) Volts	Minimum Saturation Voltage BV_R (Volts)	Minimum Q $V_R = 8 VDC$ $f = 10MHz$	Minimum Q $V_R = 8 VDC$ $f = 25MHz$	Case Style
1N5714	* 210	* 150	4.1	5.8	200	210	-	200	1
1N5715	340	250	4.1	5.8	200	210	-	200	1
1N5716	680	500	4.1	5.8	200	210	-	150	2
1N5717	680	500	4.2	-	100	115	300	-	2
1N5718	1370	1000	4.2	-	100	115	200	-	2

- Diode Capacitance @ -4VDC is Nominal ± 20%
- Diode Capacitance @ -8VDC is Nominal ± 10%

The 1N5714 thru 1N5718 are identical to 1N5421 thru 1N5425 except for package outline and meet the electrical objectives of contract DA-36-039-AMC-06181E